

# 2.1 - 2.2 GHz 2W MMIC

### FEATURES

- P.1 dB: 33 dBm
- Small Signal Gain: 29 dB
- Power Added Efficiency: 31 %
- IP3: 42 dBm
- DC Bias: 800 mA @ 7 V

### PHOTO ENLARGEMENT



### DESCRIPTION

The TC3143 is a 2 stage PHEMT MMIC power amplifier. It is designed for use in low cost and high volume 2.1-2.2 GHz ISM band applications. The MMIC provides a typical gain of 29 dB and saturation power of more than 33 dBm. Typical bias condition is 7V at 800 mA. The MMIC is a packaged in a standard SO-8 power package. The copper based carrier of the package allows direct soldering of the device to the PCB for proper heat sinking. The input and output matching of the MMIC require external components.

## **ELECTRICAL SPECIFICATIONS (Ta = 25 °C)**

| SYMBOL         | DESCRIPTION                           | MIN  | ТҮР  | MAX | UNITS |
|----------------|---------------------------------------|------|------|-----|-------|
| FREQ           | Frequency Range                       | 2.1  |      | 2.2 | GHz   |
| SSG            | Small Signal Gain                     | 28   | 29   |     | dB    |
| P.1 dB         | Output Power at 1 dB Gain Compression | 32   | 33   |     | dBm   |
| P.3 dB         | Output Power at 3 dB Gain Compression | 33   | 34   |     | dBm   |
| IP3            | Third Order Intercept Point           | 40   | 42   |     | dBm   |
| VSWR, IN       | Input VSWR                            |      | 2:1  |     | -     |
| VDD            | Supply Voltage                        |      | 7    |     | Volt  |
| Vg             | Gate Voltage                          | -0.6 | -1.2 | -2  | Volt  |
| IDD            | Current Supply Without RF             |      | 800  |     | mA    |
| IDP.1          | Current Supply @ Pout = $P_{-1} dB$   |      | 920  |     | mA    |
| η <sub>a</sub> | Power Added Efficiency                |      | 31   |     | %     |



#### **Absolute Maximum Ratings**

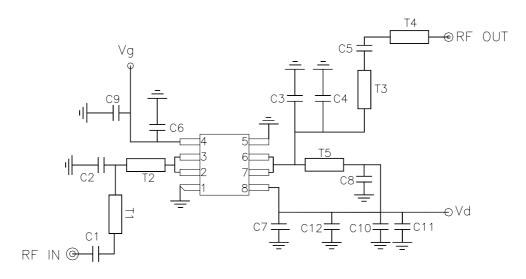
| Symbol           | Parameter/Conditions Min      |     | Max. | Units |
|------------------|-------------------------------|-----|------|-------|
| V <sub>dd</sub>  | Drain-Source Voltage          |     | 12   | Volts |
| I <sub>dd</sub>  | Total Drain Current           |     | 2000 | mA    |
| P <sub>in</sub>  | RF Input Power                |     | 10   | dBm   |
| Pt               | Power Dissipation             |     | 7    | W     |
| T <sub>ch</sub>  | Operating Channel Temperature |     | 175  | °C    |
| T <sub>STG</sub> | Storage Temperature           | -65 | 175  | °C    |

#### Note:

- 1. This GaAs MMIC is susceptible to damage from Electrostatic Discharge. Proper precautions should be used when handling these devices.
- 2.Specifications subject to change without notice.

# **TEST CIRCUITS**

**Evaluation Board Schematic** 



**TRANSCOM, INC.,** 90 Dasoong 7th Road, Tainan Science-Based Industrial Park, Hsin-She Shiang, Tainan County Taiwan, R.O.C.Web-Site: www.transcominc.com.twPhone: 886-6-5050086Fax: 886-6-5051602

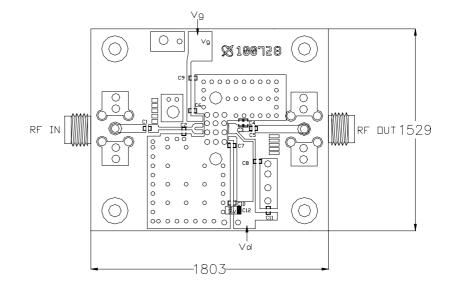


# TC3143 REV0\_20040402

## **EVALUATION BOARD**

PCB Material: FR4 ER = 4.6 Thickness = 31 mil Unit: mil

- DXF file of the PCB can be downloaded from our web-site at <u>www.transcominc.com.tw</u>
- Application Notes: For better heat sinking and grounding, it's recommended to have the via holes beneath TC3141 filled with solder and have two screws besides TC3141 installed on the PCB area



#### **Evaluation Board Parts List**

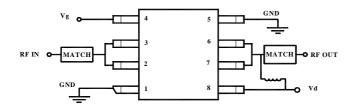
| Part Type | <b>Reference Designator</b> | Description             | Manufacturer | Part Number     |
|-----------|-----------------------------|-------------------------|--------------|-----------------|
| Capacitor | C1                          | 5 pF 0603               | Murata       | GRM39C0G3R3C50V |
| Capacitor | C2                          | 3 pF 0603               | Murata       | GRM39C0G2R5C50V |
| Capacitor | C3                          | 1.5 pF 0603             | Murata       | GRM39C0G010C50V |
| Capacitor | C4                          | 2.2 pF                  | Murata       | GRM39C0GR75C50V |
| Capacitor |                             | 5 pF 0603               | Murata       | GRM39C0G1R5C50V |
| Capacitor | C6~8                        | 1000 pF 0603            | Murata       | GRM39C0G102J50V |
| Capacitor | C9~11                       | 0.1 uF 0603             | Murata       | GRM39Y5V104Z25V |
| Capacitor | C12                         | 4.7uF 1206 Tantalum Cap |              |                 |

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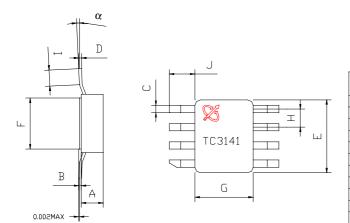
TC3143 REV0\_20040402

# CONNECTION DIAGRAM AND PIN DESCRIPTIONS



| Pin # | Name           | Description                            |
|-------|----------------|--|
| 2, 3  | RF IN          | RF input (internally DC blocked)       |
| 1, 5  | GND            | Ground                                 |
| 4     | Vg             | FET gate bias                          |
| 6, 7  | RF OUT         | RF output and V <sub>d2</sub> External |
|       |                | matching circuit required              |
| 8     | V <sub>d</sub> | Input stage drain bias                 |

# PHYSICAL DIMENSIONS (Unit: inch)



| DIMENSION | MINIMUM | NOMINAL | MAXIMUM |
|-----------|---------|---------|---------|
| A         | 0.083   | 0.086   | 0.089   |
| В         | 0.007   | 0.008   | 0.009   |
| C         | 0.017   | 0.020   | 0.023   |
| D         | 0.007   | 0.008   | 0.009   |
| E         | 0.195   | 0.200   | 0.205   |
| F         | 0,135   | 0.140   | 0.145   |
| G         | 0.155   | 0.160   | 0.165   |
| Н         |         | 0.050   |         |
| I         | 0.020   |         | 0.040   |
| J         | 0.055   | 0.065   | 0.075   |
| α         | 0°      |         | 7°      |

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